



Identification of amplitude and timing jitter in external-cavity mode-locked semiconductor lasers

Mulet, Josep; Mørk, Jesper; Kroh, Marcel

Published in:
2004 CLEO/IQEC Technical Digest CD-Rom

Publication date:
2004

Document Version
Publisher's PDF, also known as Version of record

[Link back to DTU Orbit](#)

Citation (APA):
Mulet, J., Mørk, J., & Kroh, M. (2004). Identification of amplitude and timing jitter in external-cavity mode-locked semiconductor lasers. In 2004 CLEO/IQEC Technical Digest CD-Rom

General rights

Copyright and moral rights for the publications made accessible in the public portal are retained by the authors and/or other copyright owners and it is a condition of accessing publications that users recognise and abide by the legal requirements associated with these rights.

- Users may download and print one copy of any publication from the public portal for the purpose of private study or research.
- You may not further distribute the material or use it for any profit-making activity or commercial gain
- You may freely distribute the URL identifying the publication in the public portal

If you believe that this document breaches copyright please contact us providing details, and we will remove access to the work immediately and investigate your claim.

Identification of amplitude and timing jitter in external-cavity mode-locked semiconductor lasers

Josep Mulet

*Research Center COM, Technical University of Denmark, Building 345V, DK-2800 Kgs. Lyngby (Denmark)
Departament de Física, Universitat de les Illes Balears, E-07122 Palma de Mallorca (Spain)
Phone: +34 971 172536, Fax: +34 971 173426, Email: mulet@imedea.uib.es*

Jesper Moerk

*Research Center COM, Technical University of Denmark, Building 345V, DK-2800 Kgs. Lyngby (Denmark)
Phone: +45 4525 5765, Fax: +45 4593 6581, Email: jm@com.dtu.dk*

Marcel Kroh

*Heinrich-Hertz-Institut für Nachrichtentechnik Berlin GmbH, Einsteinufer 37, D-10587 Berlin (Germany)
Phone: +49 30 31002 633, Fax: +49 30 31002 241, Email: kroh@hhi.de*

Abstract: We theoretically and experimentally investigate the dynamics of external-cavity mode-locked semiconductor lasers, focusing on stability properties, optimization of pulsewidth and timing jitter. A new numerical approach allows to clearly separate timing and amplitude jitter.

© 2004 Optical Society of America

OCIS codes: (140.5960) Semiconductor lasers; (140.4050) Mode-locked lasers; (320.7120) Ultrafast phenomena

Mode-locked semiconductor lasers are compact and efficient short-pulse sources with a number of different applications. However, due to the complex dynamics and dispersion properties of the gain and absorber media incorporated into the laser, the stability as well as the emerging pulse and noise properties are not yet understood in detail. We apply a fully distributed time-domain model [1] to theoretically investigate the dynamical properties of external-cavity mode-locked semiconductor lasers (ECMLL) [2] and compare with experimental results. The device studied is a two-section buried heterostructure with 6 QWs, 50 μm saturable absorber, and 560 μm amplifier (SOA). The position of the diffraction grating in the external cavity is adjusted to achieve 10 GHz repetition rate.

Different operation regimes appear upon variation of the reverse bias and injection current, cf. Fig. 1. The device-parameters have been optimized in order to extend the regime of stable mode-locking (ML). When the unsaturated losses are large and the current is close to threshold, regimes of weakly and fully developed Q-switching ML are obtained. The tendency to Q-switch is reduced when lowering the optical losses, e.g. by using HR mirrors, short absorbers, low internal losses, and lasing near the absorption edge. From these observations, it turns out that operation in the red side of the gain spectrum is convenient in terms of stability of the ECMLL. On the other hand, incomplete ML dominates for low reverse bias and higher currents. In the time domain, the onset of incomplete ML manifests itself in optical pulses containing a non-steady multiple peaked structure. The optimum operation point, providing the shortest optical pulses in Fig. 1, is obtained for large reverse bias and close-to-threshold operation, in good agreement with experimental findings. The changes in pulsewidth arise from pulse shaping by the grating and fast effects explicitly introduced in the absorber and amplifier models. We find a distinctive trade-off between pulsewidth and stability. The pulsewidth can thus be further reduced down to ~ 1 ps (uncompressed pulse) by increasing the bandwidth of the grating or operating at a shorter wavelength, but at the expense of a reduction of the regime of stable ML.

The measurement of timing jitter using the RF-spectrum relies on integration of the noise skirts around successive harmonic peaks [3]. For lasers operating at high repetition frequencies, however, this method becomes impractical since it requires the measurement of harmonics at very high frequencies. Hence, in most cases only the first harmonic is considered, which may be problematic when components of the timing jitter fall in a frequency range with important amplitude fluctuations. We have developed an alternative numerical method based on detecting in real-time the mean pulse position and energy. This approach allows to unambiguously distinguish timing fluctuations from amplitude noise, and establishes a connection between our fully-distributed model and the master equation theory [4].

In Fig. 2(a), we show the phase noise spectra obtained from the two methods. The higher levels of phase noise in the RF-spectrum arise from amplitude fluctuations. We observe that these differences are relevant beyond ~ 10 MHz. In panel 2(b) we compare the predicted timing jitter integrating the phase noise from 1 MHz up to the Nyquist frequency. The curves agree only at low frequencies. For integration beyond 10 MHz, the jitter obtained from the first harmonic peak in the RF-spectrum increases as a result of amplitude fluctuations, leading to an overestimate of the real timing jitter. The suitable integration limit depends on the particular device and the operation conditions, because of the damping and position of the relaxation oscillations with respect the harmonic peak.

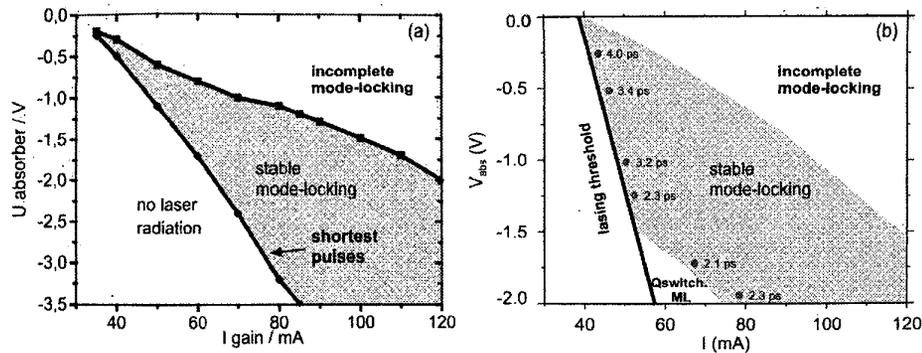


Fig. 1. Experimental (a) and simulated (b) operation regimes of a 10 GHz ECMLL composed by $50 \mu\text{m}$ absorber, $560 \mu\text{m}$ SOA and $20 \mu\text{m}$ transition region. The numbers annotated in (b) correspond to the uncompressed pulsewidths.

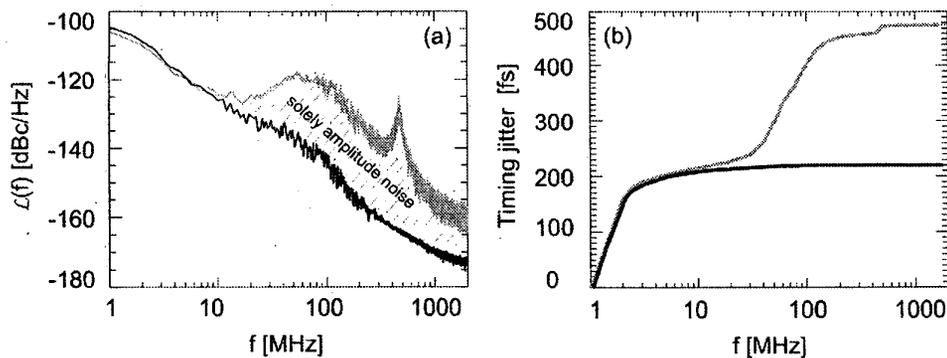


Fig. 2. Passive 4 GHz ECMLL operating 1.5 times threshold. (a) Constructed phase noise and (b) integrated timing jitter. Black lines are obtained from direct pulse detection whereas grey lines are calculated from the RF-spectrum.

This work has been supported by the project TOPRATE IST-2000-28657.

- [1] S. Bischoff et al., "Monolithic colliding pulse mode-locked semiconductor laser", *Quantum and Semiclass. Opt.* **9**, 655-674 (1997).
- [2] K. Yvind et al., "Performance of external cavity mode-locked semiconductor lasers employing reverse biased saturable absorbers", *Physica Scripta*. T101, 129-132 (2002).
- [3] D. Von der Linde, "Characterization of the noise in continuously operating mode-locked lasers", *Appl. Phys. B* **39**, 201-217 (1986).
- [4] L.A. Jang et al., "Noise of mode-locked semiconductor lasers", *IEEE J. of Selected Topics in Quantum Electron.* **7**, 159-167 (2001); and references therein.